### ESD Diodes

# **Panasonic**

# MAZC062D

### Silicon planar type

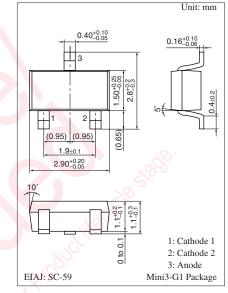
For surge absorption circuit

#### Features

- Low joint capacity zener diode
- Two elements anode-common type

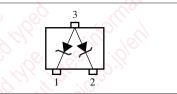
Absolute Maximum Ratings $T_a = 25^{\circ}C$						
Parameter	Symbol	Rating	Unit			
Repetitive peak forward current	I <sub>FRM</sub>	200	mA			
Power dissipation*	P <sub>D</sub>	200	mW			
Junction temperature	Tj	150	°C			
Storage temperature	T <sub>stg</sub>	-55 to +150	°C			

Note) \*: P<sub>tot</sub> = 200 mW achieved with a printed circuit board.



Marking Symbol: 6.2C

#### Internal Connection



Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA		0.9	1.0	V
Zener voltage*	VZ	$I_Z = 5 \text{ mA}$	5.9		6.5	V
Zener rise operating resistance	R <sub>ZK</sub>	I <sub>Z</sub> = 0.5 mA			100	Ω
Zener operating resistance	R <sub>Z</sub>	$I_Z = 5 \text{ mA}$		30	Ω	
Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5.5 V			3	μΑ
Terminal capacitance	Ct	$V_R = 0 V, f = 1 MHz$		8		pF

#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

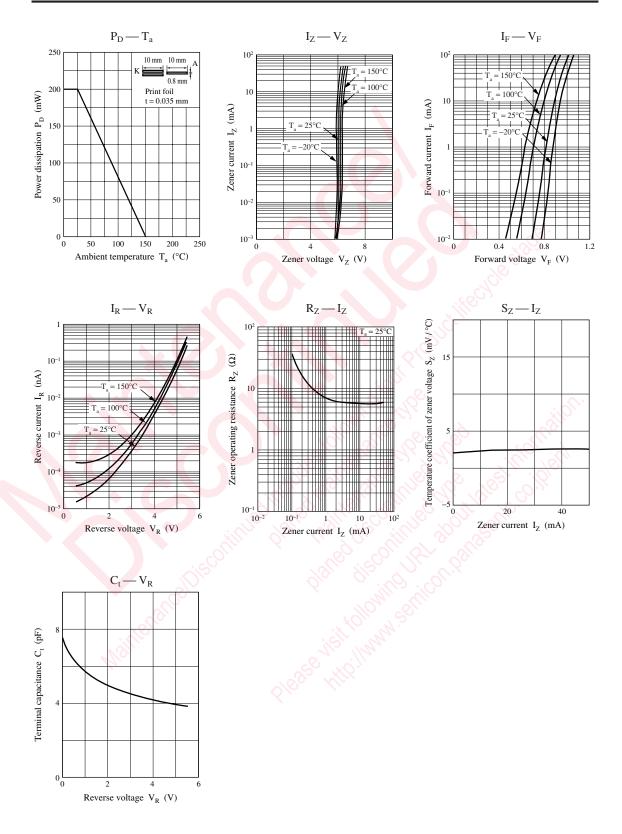
2. Absolute frequency of input and output is 5 MHz

3. Electrostatic breakdown voltage:  $\pm 15$  kV Test method: IEC-801 (C = 150 pF, R = 330  $\Omega$ , Contact discharge: 10 times) Test unit: ESS-200AX

4. \*: The  $V_Z$  value is for the temperature of 25°C. In other cases, carry out the temperature compensation. Guaranteed at 20 ms after power application.

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